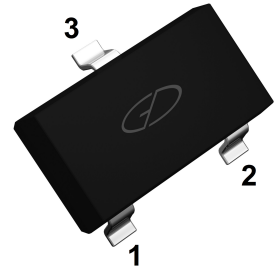


**Features**

- Low turn-on voltage
- Fast switching
- PN junction guard ring for transient and ESD protection

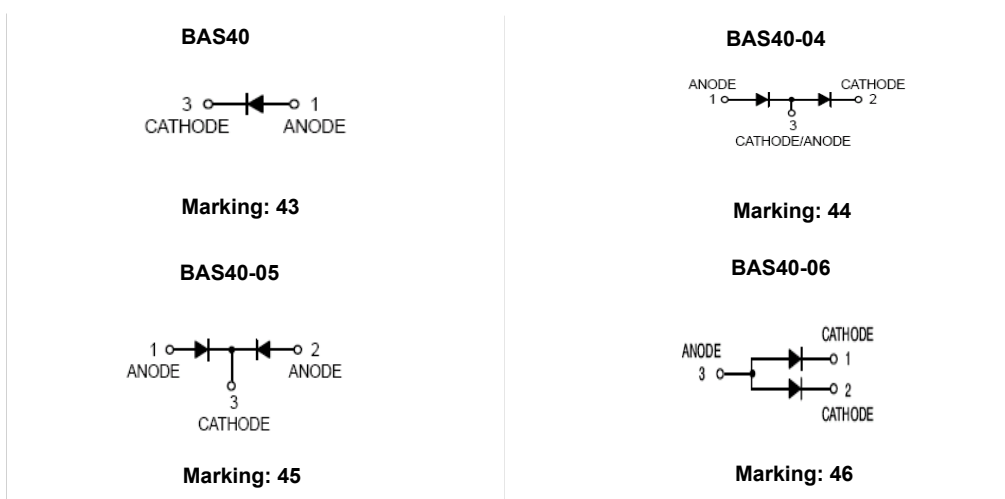


**SOT-23**

**Applications**

- High speed switching applications
- Circuit protecting
- Voltage clamping

**Schematic Diagram and Marking**



**Maximum Ratings** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	40	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Reverse Voltage	$V_R$		
Forward Continuous Current	$I_{FM}$	200	mA
Power Dissipation	$P_d$	350	mW
Forward Surge Current	$I_{FSM}$	600	mA
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	$T_j$	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	-65 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage	$V_{(BR)R}$	40	-	-	V	$I_{RS} = 10\mu\text{A}$
Forward Voltage	$V_F$	-	-	380 1000	mV	$t_P < 300\mu\text{s}, I_F = 1.0\text{mA}$ $t_P < 300\mu\text{s}, I_F = 40\text{mA}$
Reverse Leakage Current	$I_R$	-	20	200	nA	$t_P < 300\mu\text{s}, V_R = 30\text{V}$
Junction Capacitance	$C_j$	-	4.0	5.0	pF	$V_R = 0\text{V}, f = 1.0\text{MHz}$
Reverse Recovery Time	$t_{rr}$	-	-	5.0	ns	$I_F = I_R = 10\text{mA}$ to $I_R = 1.0\text{mA}, R_L = 100\Omega$

**Typical Characteristic Curves** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

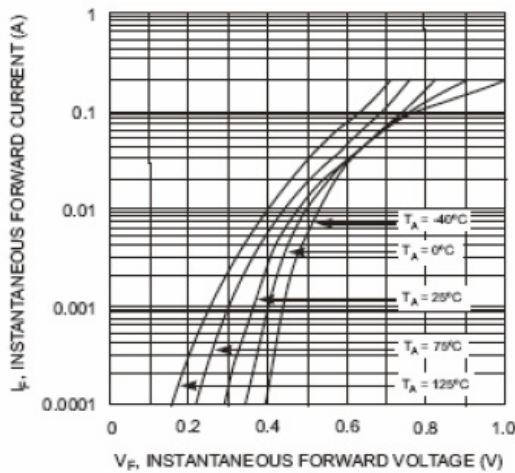


Fig. 1 Typical Forward Voltage

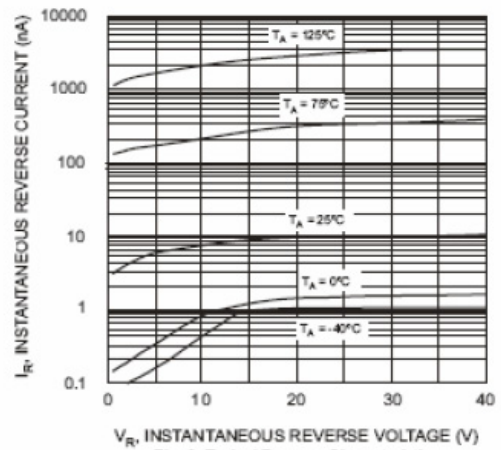


Fig. 2 Typical Reverse Characteristics

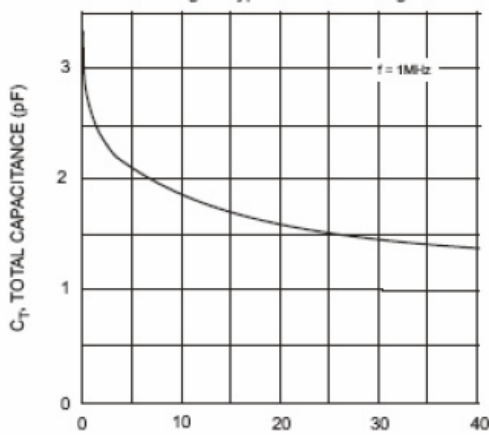


Fig. 3 Typical Capacitance

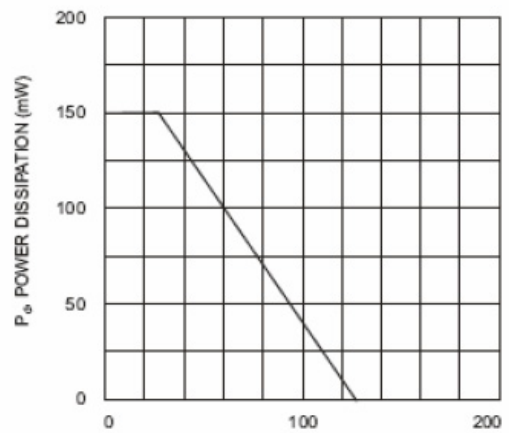
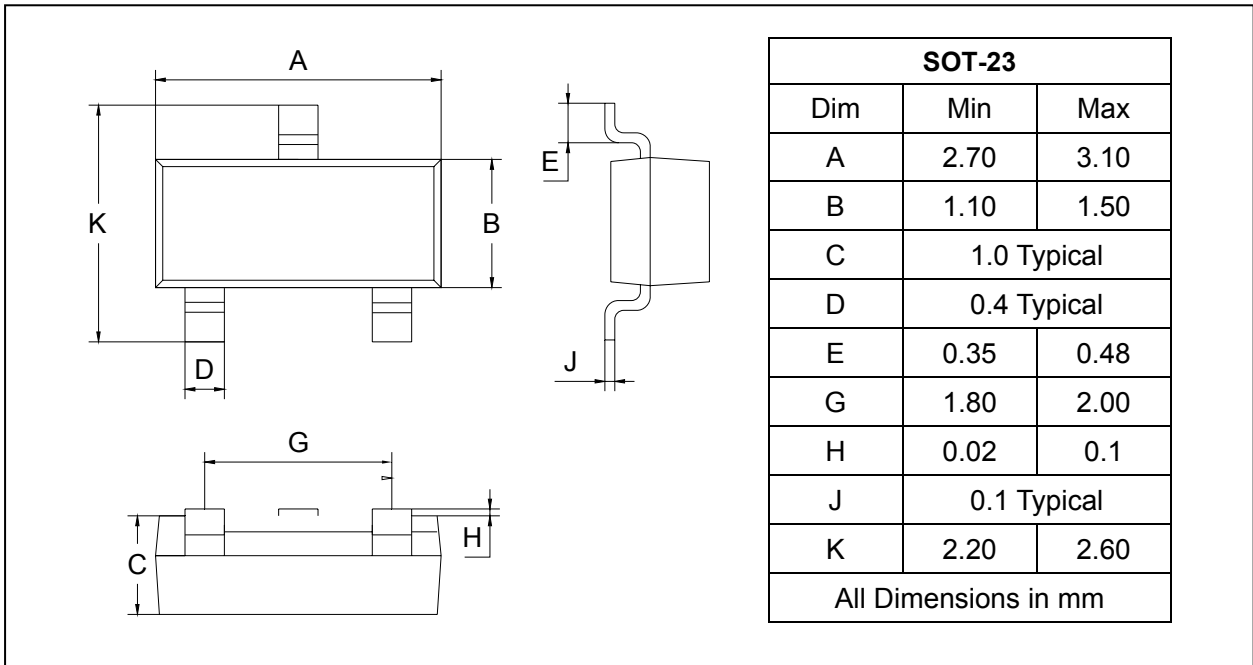


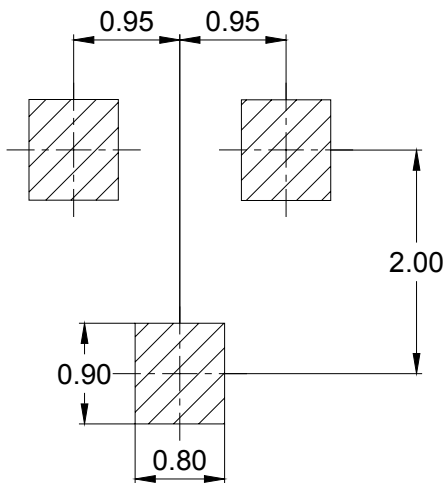
Fig. 4 Power Derating Curve, Total Package

**Package Outline Dimensions**

**SOT-23**



**Suggested Soldering Pad**



Unit : mm